
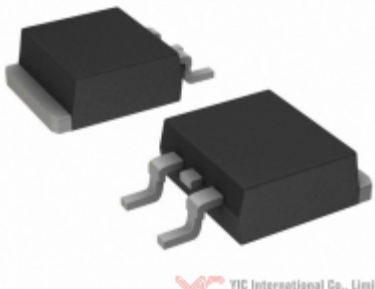








	<h2 style="color: red;">FDB10AN06A0</h2>
	<p>Manufacturer Part Number: FDB10AN06A0</p> <p>Manufacturer/Brand: AMI Semiconductor / ON Semiconductor</p> <p>Part of Description: MOSFET N-CH 60V 75A TO-263AB</p> <p>Datasheets:  FDB10AN06A0.pdf</p> <p>RoHs Status:  Lead free / RoHS Compliant</p> <p>Stock Condition: New original, 38990 pcs Stock Available.</p> <p>Ship From: Hong Kong</p> <p>Shipment Way: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Specifications

Part Number	FDB10AN06A0
Manufacturer	AMI Semiconductor / ON Semiconductor
Description	MOSFET N-CH 60V 75A TO-263AB
Category	Discrete Semiconductor Products > Transistors - FETs,
Part Status	38990 pcs Stock
Detailed Description	N-Channel 60V 12A (Ta), 75A (Tc) 135W (Tc) Surface
Series	PowerTrench®
Technology	MOSFET (Metal Oxide)
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Surface Mount
Package / Case	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device Package	TO-263AB
Power Dissipation (Max)	135W (Tc)
FET Type	N-Channel
FET Feature	-
Drain to Source Voltage (Vdss)	60V
Current - Continuous Drain (Id) @ 25°C	12A (Ta), 75A (Tc)
Rds On (Max) @ Id, Vgs	10.5 mOhm @ 75A, 10V
Vgs(th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	37nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	1840pF @ 25V
Drive Voltage (Max Rds On, Min Rds On)	6V, 10V
Vgs (Max)	±20V
Packaging	Tape & Reel (TR)
Lead Free Status / RoHS Status	Lead free / RoHS Compliant
Moisture Sensitivity Level (MSL)	1 (Unlimited)

FDB10AN06A0 is New Original in Stock, Search FDB10AN06A0 Datasheets, PDF, Inventory at Y-IC.com Online, Order FDB10AN06A0 AMI Semiconductor / ON Semiconductor with warrantied and confidence. RFQ FDB10AN06A0 : Info@Y-IC.com

You May Be Also Be interested In:

 <p>FDB088N08 AMI Semiconductor / ON Semiconductor MOSFET N-CH 75V 75A D2PAK</p>	 <p>FDB10N20C VB FDB10N20C VB</p>	 <p>FDB110N15A AMI Semiconductor / ON Semiconductor MOSFET N-CH 150V 92A D2PAK</p>	 <p>FDB10AN06A0 FAI FDB10AN06A0 FAI</p>
 <p>FDB110N15A Fairchild/ON Semiconductor MOSFET N-CH 150V 92A D2PAK</p>	 <p>FDB088N08 Fairchild/ON Semiconductor MOSFET N-CH 75V 75A D2PAK</p>	 <p>FDB10AN06A0 Fairchild/ON Semiconductor MOSFET N-CH 60V 75A TO-263AB</p>	 <p>FDB082N15A Fairchild/ON Semiconductor MOSFET N-CH 150V 117A D2PAK</p>

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FDB045AN08A0	FDB045AN08_F085	FDB047N10	FDB047N10	FDB050AN06A0
FDB050AN06A0	FDB050AN06A0	FDB060AN08A0	FDB060AN08A0	FDB060AN08A0
FDB070AN06A0	FDB070AN06A0	FDB070AN06_F085	FDB075N15A	FDB075N15A
FDB075N15A_F085	FDB082N15A	FDB082N15A	FDB088N08	FDB088N08
FDB10AN06A0	FDB10AN06A0	FDB10N20C	FDB110N15A	FDB110N15A
FDB120N10	FDB120N10	FDB12N50	FDB12N50F	FDB12N50FTM
FDB12N50FTM_WS	FDB12N50TM	FDB12N50TM	FDB12N50U	FDB12N50UTM
FDB12N50UTM_WS	FDB12N50UTM_WS	FDB12P10	FDB13AN06A	FDB13AN06A0
FDB13AN06A0	FDB13AN06A0	FDB13N06A0	FDB14AN06LA0	FDB14AN06LA0

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